

Divergence of the localization length in quantum Hall systems

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The localization properties of a two-dimensional disordered electron gas in a strong external magnetic field are studied. The impurities are considered to be located on a square lattice with random amplitudes. The concentration of these impurities is low, i.e., the average distance between the impurities exceeds the magnetic length. For short-ranged impurity potentials we analytically obtain an exponent $\nu = 2/3$ for the divergence of the localization length at the lowest Landau level. The density of states is also calculated.

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One of the important features of Quantum Hall systems is the competition between localized states and extended states. In the absence of a magnetic field all states are localized in a two-dimensional disordered system, whereas with a sufficiently strong magnetic field the states at the Landau levels are extended. This behavior can be described by a diverging localization length ξ at the Landau levels E_n , which scales with energy as $\xi \sim |E - E_n|^{-\nu}$. This transition is studied in two types of experiments. The first one, pioneered by Wei *et al.* [1] measured the temperature dependent magneto-resistivity in *InGaAs/InP* heterostructures and showed that the half-width ΔB , of the transition regime where ρ_{xx} is nonzero, vanishes as $\Delta B \sim T^\kappa$, with $\kappa = 0.42 \pm 0.04$ independent of the Landau level index. B is the applied magnetic field. Later on Koch *et al.* [2] measured values of κ ranging between 0.36 and 0.81 for *AlGaAs/GaAs* systems. This exponent κ , arises from a competition between the phase coherence length, which scales with temperature as $L_\Phi \sim T^{-p/2}$, and the localization length ξ . Using scaling arguments [3] these exponents can be combined to show that the temperature dependence of ρ_{xx} in the transition regime is controlled by the exponent $\kappa = p/2\nu$. Very recently Wei *et al.* [4] measured p with an electron heating experiment in a *InGaAs/InP* system and found $p \simeq 2$. Combining all this together yields for the exponent $\nu \simeq 2.38$. The value $p = 2$ corresponds to the electron-electron scattering value [5] with no external magnetic field. The interpretation of the experiments therefore remains unclear. The other type of experiment measures the system-size dependence of the width in the transition regime of the ρ_{xx} peak. These measurements were undertaken by Koch *et al.* [6] on *AlGaAs/GaAs* heterojunctions and they found $\nu = 2.3 \pm 0.1$. For κ they measured $\kappa = 0.68 \pm 0.04$. Here again the interpretation remains to be studied. For, in order to be meaningful, this experiment requires the phase coherence length L_Φ to exceed the system length L . This would however induce quantum mesoscopic conductance fluctuations which are not observed in these experiments. Another point which remains undecided is the importance of *electron-electron* correlations in these experiments.

Analytically no general results for the exponent exist [7]. But in the limit of a very smooth disorder potential the problem can be mapped onto a classical percolation picture [8] and yields $\nu = 4/3$. Mil'nikov and Sokolev [9] included quantum tunneling and obtained $\nu = 7/3$. Using perturbation theory Hikami [10] calculated the inverse participation number, which yields $\nu \simeq 2.4$ when analyzed in terms of multifractality [11]. Other results are obtained numerically. We mention here only the more recent results [7]. Two main approaches can be identified. The first one studies numerically the Thouless-number; using this method Ando [12] has shown that the exponent ν is independent of the type of scattering, i.e., long-range or short-range. He moreover obtains $\nu \simeq 2$ for the lowest Landau level. The other class of numerical studies uses the finite-size scaling method. Recent results include the approach of Huckestein and Kramer [13] who introduced a random-matrix model in which matrix elements of the Hamiltonian are given by a random complex number resulting in correct moments up to second order. Their latest result for the lowest Landau level is $\nu = 2.35 \pm 0.03$. Another very recent numerical result has been obtained by Liu and Das Sarma [14] using a transfer matrix combined with the finite-size scaling method. They studied different impurity concentrations and potential ranges. For the lowest Landau level they obtain values for ν ranging from 1.86 to 2.32. All these numerical studies consider a dense concentration of impurities, relative to the magnetic length $l_0 = \sqrt{\hbar c/eB}$, where the localization length diverges only in the limit when the width of the system tends to infinity.

In this letter we consider the opposite limit, where the concentration of impurities is low enough to maintain at least one extended state at the lowest Landau level. This extended state appears even if the system size is not infinite. The impurities we consider are placed on a lattice of constant d and their amplitudes are taken randomly. Furthermore we suppose that no Landau level mixing is present as we consider very high magnetic fields and we restrict ourselves to the lowest Landau level. The system is mapped onto a one dimensional disordered discrete tight-binding equation using as a basis the Landau

functions. Only the nearest neighbors are considered as relevant, which is a valuable approximation, as we examine a sufficiently large elementary lattice of width a . The resulting one dimensional diluted Anderson model can be solved exactly at the lowest Landau level E_0 and yields an infinite localization length. Around this energy the localization length ξ can be evaluated and scales as $\xi \sim (E - E_0)^{-2/3}$ for short-ranged impurity potentials. This demonstrates that we are in a different universality class than the models studied numerically. In addition, the density of states is found to scale as $\rho \sim (E - E_0)^{-1/3}$.

We start by considering a two-dimensional plane of size $L_X \times L_Y$. In this plane we put a rectangle filled with impurities whose dimension is $N \times M$. The sizes L_X and L_Y are essentially meant to be infinite, whereas N and M are finite. In particular M stays finite when we take the limit $N \rightarrow \infty$. Therefore the localization properties are studied in the X direction. We start with the usual Hamiltonian with a magnetic field and a disordered potential $V(x, y)$. In the Landau gauge, with the vector potential $\vec{A} = (By, 0, 0)$, where B is the perpendicular magnetic field, the Landau wave-functions $\Psi_{n,k}$ are eigenfunctions of the Hamiltonian without disorder and the spectrum is given by the Landau levels $E_n = \hbar\omega_c(n + 1/2)$, where $\omega_c = eB/mc$ is the cyclotron frequency. The Landau-wave functions of the lowest Landau level are

$$\Psi_{0,k} = N_0 e^{ikx} e^{-(y - kl_0^2)^2 / 2l_0^2}, \quad (1)$$

where $N_0 = 1/\sqrt{L_X l_0 \pi^{1/2}}$ and all constants are taken to be one. As we work in the very high magnetic field limit we can assume that no Landau level mixing is present, therefore we will restrict ourselves to the lowest Landau level, i.e., $E_0 = \hbar\omega_c/2$. We write the eigenfunction of the Hamiltonian with disorder as

$$\Psi(x, y) = \int_{k=-\infty}^{\infty} \alpha(k) \Psi_{0,k}(x, y) dk. \quad (2)$$

We further suppose that we have a crystal of lattice spacing a and rewrite (2) in this new basis as

$$\Psi(x, y) = \sum_{l=-\infty}^{\infty} \psi_l |l\rangle, \quad (3)$$

where $\alpha(k) = \sum_{l=-\infty}^{\infty} \psi_l e^{-ikla}$ and

$$|l\rangle = \frac{1}{\sqrt{L_Y l_0 \pi^{1/2}}} e^{-(x-la)^2 / 2l_0^2} e^{-iy(x-la)/l_0^2}. \quad (4)$$

The states $|l\rangle$ have the usual orthonormalization property, i.e., $\langle p | l \rangle = \delta_{l,p}$. Writing the Schrödinger equation using (3) gives the following discrete one-dimensional equation

$$\sum_{l=-\infty}^{\infty} D_{p,l} \psi_l = \epsilon \psi_p, \quad (5)$$

where $\epsilon = E - E_0$ and $D_{p,l} = \langle p | V(x, y) | l \rangle$. The potential of the impurities will be considered to be Gaussian, with their sites and amplitudes taken randomly. It can be expressed as follows:

$$V(x, y) = \sqrt{\frac{\lambda}{\pi}} \sum_{i=1}^N V_i e^{-\lambda(x-x_i)^2} V_y(y-y_i). \quad (6)$$

This potential yields for $D_{p,l}$

$$D_{p,l} = \overline{N_0} e^{-\frac{a^2}{8l_0^2}(l-p)^2} \tilde{V}_y(a(l-p)/l_0^2) \sum_{i=1}^N V_i e^{i\frac{a}{l_0^2}(l-p)y_i} e^{-\frac{\bar{\lambda}}{2l_0^2}\left(x_i - \frac{a(l+p)}{2}\right)^2}, \quad (7)$$

where $\tilde{V}_y$ is the Fourier transform of V_y , $\overline{N_0} = N_0 \sqrt{\lambda}$ and $\bar{\lambda} = \lambda/(\lambda + B/2)$. V_y could be any type of potential, also Gaussian. All the above expressions are obtained without any approximations. In the following, sensible approximations that rely on experimental results will be introduced. The systems we are considering are very pure samples in which the density of impurities is very low, essentially of the order of 10^{10}cm^{-2} [2]. From this it follows that the average distance between impurities is of the order of $d = 1000 \text{\AA}$. At this point it is useful to note that in the lowest Landau level the typical magnetic length is of the order of $l_0 = 100 \text{\AA}$. Therefore, the dimensionless quantity $d/l_0 \simeq 10$, hence the limit we are interested in is $d \gg l_0$. A natural assumption regarding the impurities is to consider that they are all located on a super lattice of width d where d/a is an integer. The randomness of the impurities is therefore only given by the random amplitudes of the potentials. With these assumptions the positions of the impurities can be redefined with integer coordinates on this lattice. Thus V_{ij} is the impurity amplitude at the position $(i, j)a$ and therefore in our system most V_{ij} are zero. In the usual heterojunctions the elementary width is of the order of an Ångström but as the relevant length scales of our system are essentially l_0 and d we make the following approximation: As we are mainly concerned with the effect of the impurities, the elementary width a can be rescaled to the same order of magnitude as d but with the condition $a < d$. Therefore the typical bound needed to neglect the terms $|p - l| > 1$ in (7) is $a^2 > 8l_0^2$, which is equivalent to a nearest neighbor approximation and yields

$$D_{l,l} = \overline{N_0} \tilde{V}_y(0) \sum_{i,j}^{N,M} V_{ij} e^{-\frac{\bar{\lambda} a^2}{2l_0^2} \left(\frac{d}{a} i - l\right)^2}$$

$$D_{l,l+1} = \overline{N_0} \tilde{V}_y(a/l_0^2) e^{-\frac{a^2}{8l_0^2}} \sum_{i,j}^{N,M} V_{ij} e^{i\frac{a}{l_0^2} j} e^{-\frac{\bar{\lambda} a^2}{2l_0^2} \left(\frac{d}{a} i - (l+1/2)\right)^2}. \quad (8)$$

We are now left with two types of terms: The diagonal terms $W_l \equiv D_{l,l}$ and the off-diagonal terms $D_{l+1} \equiv$

$D_{l,l+1}$. With these new definitions and using the fact that d/a is an integer, (for simplicity we will only consider even integers), we obtain the following expressions for equations (8)

$$W_{\underline{a}l} = \overline{N_0} \tilde{V}_y(0) \sum_j^M V_{l,j} \quad , \quad (9)$$

$$W_{\underline{a}l+1} = W_{\underline{a}l} \cdot e^{-\frac{\tilde{\lambda}a^2}{2l_0^2}} \quad , \quad W_{\underline{a}l+2} = W_{\underline{a}l} \cdot e^{-4\frac{\tilde{\lambda}a^2}{2l_0^2}} \quad , \quad \dots \quad (10)$$

and for the off-diagonal terms we have

$$D_{\underline{a}l+1} = D_{\underline{a}l} \quad , \quad D_{\underline{a}l+2} = D_{\underline{a}l-1} \quad , \quad \dots \quad (11)$$

These coefficients can now be inserted back in equation (5) yielding

$$(W_l - \epsilon)\psi_l + D_{l+1}\psi_{l+1} + D_l^*\psi_{l+1} = 0. \quad (12)$$

The usual procedure of transforming an off-diagonal disordered Anderson model to a diagonal disordered model [15] can now be applied, namely

$$\Psi_l = \psi_l/\phi_l \quad \text{where} \quad \phi_l^*\phi_{l-1} = 1/D_l^*. \quad (13)$$

The additional diagonal part simplifies to 1 as $|\phi_l| = 1$ due to (11). The condition that d/a is an even integer and a periodic boundary condition on the impurities is also used. The transformed equation (12) now reads

$$(W_l - \epsilon)\Psi_l + \Psi_{l+1} + \Psi_{l-1} = 0. \quad (14)$$

If $\tilde{\lambda}a^2 \gg 2l_0^2$ we can neglect the terms (10). This states that only the coefficients in the vicinity of an impurity survive, so that W_l is non-zero if l is a multiple of d/a , i.e., $W_{\underline{a}l}$ are random and $W_{\underline{a}l+1} = W_{\underline{a}l+2} = \dots = 0$

It is straightforward to see that the states at $\epsilon = 0$ are *overall extended*, as one only needs to suppose that $\Psi_{\underline{a}l} = 0$ and one is left with an ordered Anderson model. The next step consists in studying the properties of the model around $\epsilon = 0$. For this purpose we renormalize (14) in the following way

$$(W_{2l+1} - \epsilon)\Psi_{2l-2} + \Omega_{2l}(\epsilon)\Psi_{2l} + (W_{2l-1} - \epsilon)\Psi_{2l+2} = 0, \quad (15)$$

where $\Omega_{2l}(\epsilon) = W_{2l+1} + W_{2l-1} - 2\epsilon - (W_{2l+1} - \epsilon)(W_{2l-1} - \epsilon)$. Furthermore, in our diluted model $W_{2l+1} = 0$, which when inserted in (15), yields

$$\Psi_{2l-2} + (2 + \epsilon(W_{2l} - \epsilon))\Psi_{2l} + \Psi_{2l+2} = 0, \quad (16)$$

for $\epsilon \neq 0$. This last model was extensively studied in the limit $\epsilon \ll 1$ by Derrida and Gardner [16]. They calculated the complex Lyapounov exponent γ , where the

real part corresponds to the inverse localization length and the imaginary part to π times the integrated density of states. Their results can be expressed as follows:

$$\begin{cases} Re(\gamma) \simeq K_1 \epsilon^{2/3} \langle W^2 \rangle^{1/3} \\ Im(\gamma) \simeq K_2 \epsilon^{2/3} \langle W^2 \rangle^{1/3}, \end{cases} \quad (17)$$

where $K_1 = 0.29 \dots$ and $K_2 = 0.16 \dots$ and $\langle \cdot \rangle$ is the average over all impurities. From (17) it is straightforward that

$$\xi \sim \frac{1}{(E - E_0)^{2/3} \langle W^2 \rangle^{1/3}}, \quad (18)$$

and the density of states is

$$\rho(\epsilon) = \partial_\epsilon Im\gamma(\epsilon) \sim \epsilon^{-1/3}. \quad (19)$$

Besides the assumption that all impurities are located on a square lattice, we supposed that the concentration of impurities is very low. Indeed, Koch *et al.* [2] measured the quantum Hall effect for different types of scatterers. They used *AlGaAs/GaAs* heterostructures doped with either *Be* δ -like repulsive scatterers or *Si* δ -like attractive scatterers. They found that the exponent κ varied from 0.36 to 0.81 depending on the concentration of impurities, ranging from 0 to $2 \cdot 10^{10} cm^{-2}$, which corresponds to a typical distance between impurities of $d = 1000 \text{\AA}$. This is an indication that the impurity concentration might have an effect on the localization length exponent and drives the system into a different universality class, depending on the concentration. As we mentioned before the typical experimental value for d/l_0 is 10 and in our approximations we used the fact that $d > a \gg l_0$. Nevertheless, if we keep the first term of eq. (10), which corresponds to a second order approximation, we observe numerically no change of the scaling (18) and (19). This shows that we don't have a singular behavior due to the first order approximation we used in our calculations and that our results remain valid for less extreme values of d/l_0 .

Concerning the range of the potential and in order to remain consistent within our approximations, the width of the potential must be smaller or of the order of the magnetic length. Actually in the limit $\lambda \rightarrow \infty$ (δ -limit), Gredeksul *et al.* [17] previously demonstrated the existence of extended states exist in these systems. We confirm their results and generalize them to non- δ potentials and evaluate the scaling around the critical energy. Indeed in the edge state picture [18] of the Quantum Hall effect one needs either the range of the potential to be larger than the magnetic length, or $d > l_0$ if the range is shorter, when contacts are taken into account [19]. As this last condition applies, the model studied fits in well with this picture to reproduce the features of the Quantum Hall effect. For the other approaches to the Quantum Hall effect, such as the original one due to Laughlin [20], the microscopic details of the impurities are unimportant, but states must be extended at the Landau levels

and localized elsewhere, what we clearly demonstrated in this letter.

A striking point in our results is that we obtain a different exponent than most numerical studies. The comparison with experiments is less trivial as their results have still to be better understood. The numerical studies, using finite size scaling [13] [14], consider the distance d between impurities to be smaller, or of the same order than the magnetic length l_0 and more important, no extended states exist, even at the Landau level; but the localization length diverges when the width tends to infinity. The different studies are in a good agreement for a unique value of the exponent $\nu \simeq 2.35$, so that it has been conjectured that they belong to a single universality class. The case studied in this letter deals with the opposite limit, i.e., $d \gg l_0$ and we find a very different value for the exponent, namely $\nu = 2/3$. It is in fact not so surprising that this model belongs to a different universality class as there is a fundamental difference; at the Landau level we have an overall extended state, even if the system size is finite, so that the transition from an extended state to a localized one is much sharper, which in turn leads to a smaller exponent. It would however be interesting to study the crossover between both exponents, by varying the impurity concentration.

It is worthwhile noticing that if we take the random potential to be zero, this would imply that $\epsilon = 0$ in eq. (5) and that ψ_l is undefined, which reflects the degeneracy of a Landau level, so that the density of states is a δ -function centered at the Landau level. Therefore the effect of disorder is to broaden the density of states as $\epsilon^{-1/3} \langle W^2 \rangle^{1/3}$, whereby only states in the vicinity of $\epsilon = 0$ remain extended. For if we equate the length of the system with the localization length, so that the number of extended states, states whose localization length exceeds the size of the system, is independent of the size of the system, but the transmission coefficient of eq. (14) is one at $\epsilon = 0$ [21].

The main result of this letter is the derivation of the localization length exponent ν analytically in a two-dimensional disordered electron gas in a high external magnetic field. This exponent is found to be $2/3$. It is calculated for short-ranged impurity potentials when the concentration of impurities is low, i.e., when the average distance between impurities exceeds the magnetic length. Due to the low concentration of impurities, the system belongs to a different universality class than most models studied previously, which are closer to a value of ν of around 2.3. Additionally in the model studied in this letter, states remain overall extended at the center of the Landau level, even if the width of the system is not infinite as opposed to the models studied numerically; and finally the density of states exhibits the usual disorder broadening.

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